# NSN 5961-01-044-4169

Transistor - Page 1 of 1

AeroBase Group

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## **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

Between 0.250 inches and 0.450 inches

# **Overall Width:**

1.050 inches

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Terminal

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 7.50 amperes source cutoff current and 25.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

200.0 milliwatts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

02101-80807 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

2 uninsulated wire lead

#### Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0